# NSN 5961-00-563-2082

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# Inclosure Material:

Metal

**Overall Length:** 

0.450 inches

## **Overall Diameter:**

0.875 inches

# **Mounting Facility Quantity:**

2

## Internal Configuration:

Junction contact

## Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

#### Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

160.0 collector to base voltage/static/emitter open and 7.0 emitter to base voltage, static, collector open and 140.0 collector to emitter voltage/static/base open

#### **Current Rating Per Characteristic:**

30.00 amperes source cutoff current

#### Power Rating Per Characteristic:

150.0 watts small-signal input power, common-collector

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### Test Data Document:

98230-on088744 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

#### Terminal Type And Quantity:

2 pin and 1 case Shelf Life: N/a Unit Of Measure: --Demilitarization: No

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